



N-Channel 60-V (D-S) MOSFET

PRODUCT SUMMARY			
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)	
60	0.16 at V _{GS} = 10 V	2.0	
	0.22 at V _{GS} = 4.5 V	1.7	

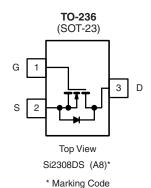
FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Power MOSFET
- 100 % R_g Tested



RoHS*

FREE Available



Ordering Information: Si2308DS-T1

Si2308DS-T1-E3 (Lead (Pb)-free)

Si2308DS-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted						
Parameter		Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	60	V		
Gate-Source Voltage		V _{GS}	± 20	V		
Continuous Drain Current /T 150 °C\a	T _A = 25 °C	I _D	2.0			
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		1.6	1		
Pulsed Drain Current ^b		I _{DM} 10		A		
Continuous Source Current (Diode Conduction) ^a						
Mariana Barra Birahada	T _A = 25 °C	P _D	1.25	W		
Maximum Power Dissipation ^a	T _A = 70 °C	1 'D	0.80]		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C		

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Maximum	Unit	
Maximum Junction-to-Ambient ^a	- R _{thJA}	100	°C/W	
Maximum Junction-to-Ambient ^c	' 'thJA	166	C/VV	

Notes:

- a. Surface Mounted on FR4 board, $t \le 5 \text{ s.}$
- b. Pulse width limited by maximum junction temperature.
- c. Surface Mounted on FR4 board.

For SPICE model information via the Worldwide Web: www.vishay.com/www/product/spice.htm

* Pb containing terminations are not RoHS compliant, exemptions may apply.

Si2308DS

Vishay Siliconix



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static			•				
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{DS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	60			V	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.5		3.0 V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current		V _{DS} = 60 V, V _{GS} = 0 V			0.5	μΑ	
	IDSS	V_{DS} = 60 V, V_{GS} = 0 V, T_{J} = 55 °C			10		
On-State Drain Current ^a		$V_{DS} \ge 4.5 \text{ V}, V_{GS} = 10 \text{ V}$	6			^	
	I _{D(on)}	$V_{DS} \ge 4.5 \text{ V}, V_{GS} = 4.5 \text{ V}$	4			Α	
Drain-Source On-State Resistance ^a		$V_{GS} = 10 \text{ V}, I_D = 2.0 \text{ A}$		0.125	0.16	Ω	
	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 1.7 \text{ A}$		0.155	0.22		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 4.5 \text{ V}, I_D = 2.0 \text{ A}$		4.6		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 1 A, V _{GS} = 0 V		0.77	1.2	٧	
Dynamic	L L			L			
Total Gate Charge	Qg			4.8	10		
Gate-Source Charge	Q_{gs}	V_{DS} = 30 V, V_{GS} = 10 V, I_{D} = 2.0 A		0.8		nC	
Gate-Drain Charge	Q_{gd}			1.0			
Gate Resistance	R_g		0.5		3.3	Ω	
Input Capacitance	C _{iss}			240			
Output Capacitance	C _{oss}	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		50		pF	
Reverse Transfer Capacitance	C _{rss}			15			
Switching	<u> </u>			1	<u> </u>		
Turn-On Delay Time	t _{d(on)}			7	15		
Rise Time	t _r	V_{DD} = 30 V, R_L = 30 Ω		10	20	ns	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 4.5 V, R_g = 6 Ω		17	35		
Fall Time	t _f			6	15		

Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

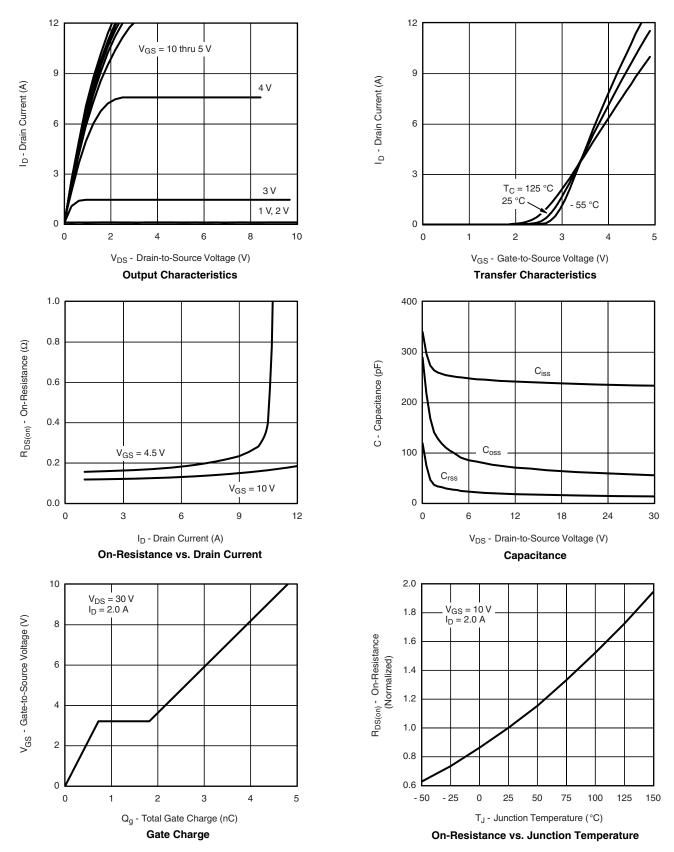
a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$







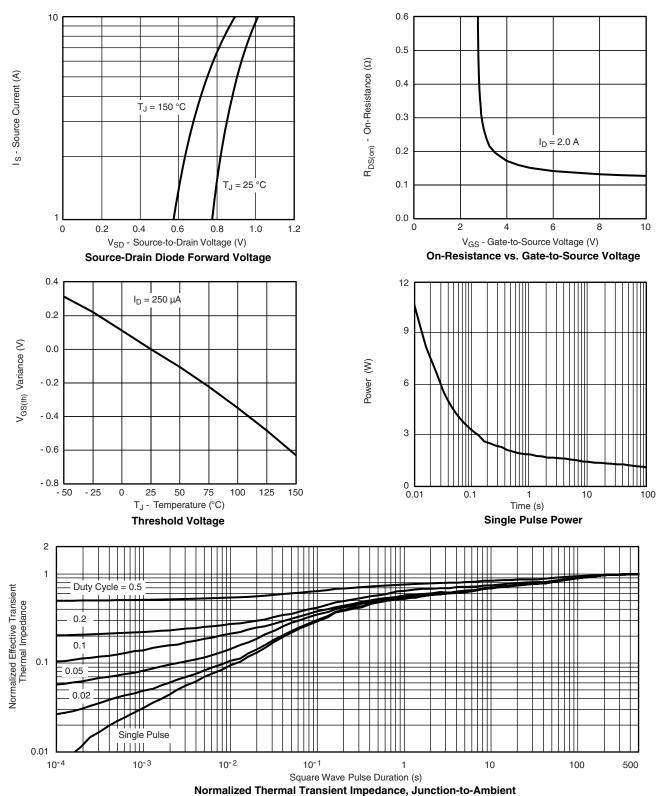
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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